

NPN SILICON RF TRANSISTOR **2SC4228**

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 3-PIN SUPER MINIMOLD

DESCRIPTION

The 2SC4228 is a low supply voltage transistor designed for VHF, UHF low noise amplifier.

It is suitable for a high density surface mount assembly since the transistor has been applied 3-pin super minimold package.

FEATURES

- Low noise : NF = 1.9 dB TYP. @ VcE = 3 V, Ic = 5 mA, f = 2 GHz
 - High gain : $|S_{21e}|^2 = 7.5 \text{ dB TYP}$. @ Vce = 3 V, Ic = 5 mA, f = 2 GHz
- 3-pin super minimold package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
2SC4228	50 pcs (Non reel)	• 8 mm wide embossed taping
2SC4228-T1	3 kpcs/reel	Pin 3 (Collector) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office. The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	VCEO	10	V
Emitter to Base Voltage	VEBO	1.5	V
Collector Current	lc	35	mA
Total Power Dissipation	Ptot Note	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	–65 to +150	°C

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

The mark \star shows major revised points.

ELECTRICAL CHARACTERISTICS (TA = +25°C)

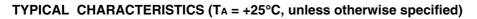
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics							
Collector Cut-off Current	Ісво	Vсв = 10 V, IE = 0 mA	-	-	1.0	μA	
Emitter Cut-off Current	Іево	Vев = 1 V, Ic = 0 mA	-	-	1.0	μA	
DC Current Gain	hfe Note 1	Vce = 3 V, Ic = 5 mA	50	100	250	-	
RF Characteristics							
Gain Bandwidth Product	fт	Vce = 3 V, Ic = 5 mA, f = 2 GHz	5.5	8.0	-	GHz	
Insertion Power Gain	S _{21e} ²	Vce = 3 V, Ic = 5 mA, f = 2 GHz	5.5	7.5	-	dB	
Noise Figure	NF	Vce = 3 V, Ic = 5 mA, f = 2 GHz	-	1.9	3.2	dB	
Reverse Transfer Capacitance	Cre ^{Note 2}	$V_{CB} = 3 V$, $I_E = 0 mA$, $f = 1 MHz$	-	0.3	0.7	pF	

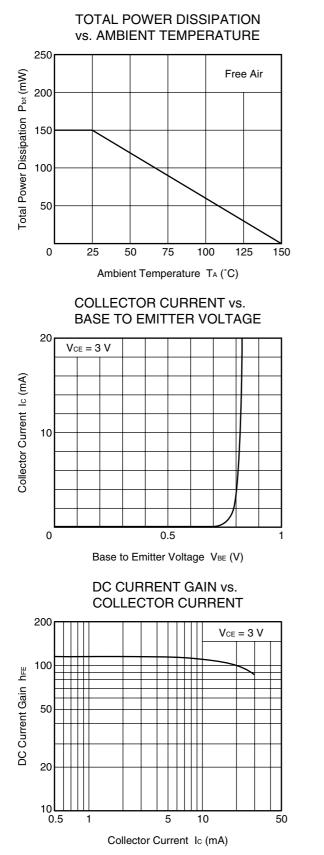
Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

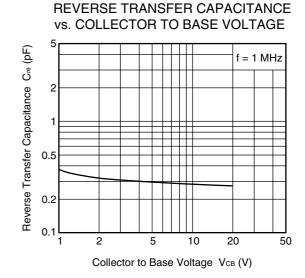
hfe CLASSIFICATION

Rank	R43	R44	R45
Marking	R43	R44	R45
hfe Value	50 to 100	80 to 160	125 to 250

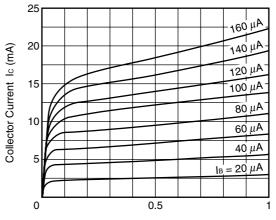




Remark The graphs indicate nominal characteristics.

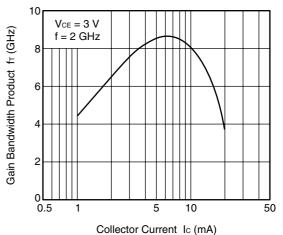


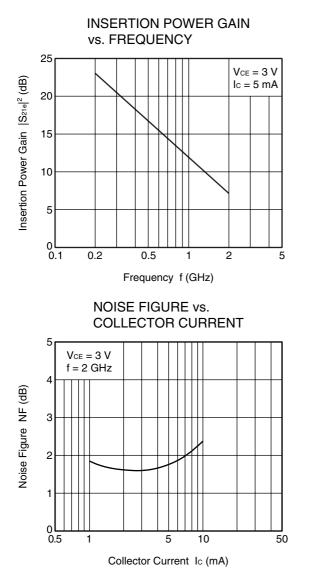
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



Collector to Emitter Voltage VCE (V)

GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT







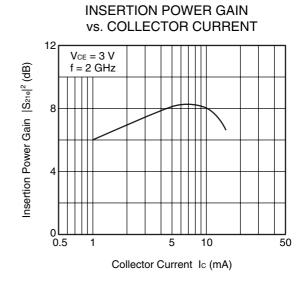
S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

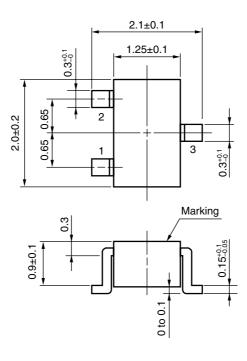
 $[\text{RF and Microwave}] \rightarrow [\text{Device Parameters}]$

URL http://www.ncsd.necel.com/



PACKAGE DIMENSIONS

3-PIN SUPER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

Emitter
 Base

3. Collector

(EIAJ : SC-70)

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